

Index

a

- A₂-A₁-D-A₁-A₂ type SMAs
 - with benzotriazole 325–328
 - with quinoxaline 328
- absorption coefficient 49, 54–56, 60, 62, 63, 78, 83, 94, 101, 105, 136, 172, 182, 183, 192, 193, 198, 201, 229, 235, 252, 253, 255, 268, 283, 289, 299, 300, 302, 303, 317, 458, 479, 483, 575, 603
- absorption spectrum 24, 47, 56, 158, 160, 163, 166, 181, 208, 249, 254, 262, 263, 265, 268, 300, 358, 361, 462, 473, 474, 562, 592, 594–597, 603, 605, 606
- acceptor-donor-acceptor (A–D–A) NFAs
 - based on heteroheptacenes
 - with sp³-hybridized bridging atoms 226–231
 - without sp³-hybridized bridging atoms 231–233
 - based on ladder-type heteroacenes 223–236
 - heteropentacenes and heterohexacenes 224–226
 - from non-covalent locked building blocks 235
- acceptor-donor-acceptor (A–D–A)-type SMAs
 - core units engineering
 - asymmetric cores 184–194
 - IDTT and derivatives 167–176
 - non-fused cores 194–200
 - spacer unit effects 176–184
 - end groups engineering 164–167
 - IDIC 163
 - ITIC 160
 - side chains optimization 160–163
 - structure 160
- acenaphtho[1,2-*b*]quinoxaline acceptor units 35
- acetophenone (AP) 544
- active layer materials 77, 218, 315, 381, 383–397, 400, 401, 406, 418, 448, 449, 488, 615, 618
- A–D–A-type oligothiophenes 79
- A–DA'D–A type SMAs
 - benzo[*c*][1,2,5]thiadiazole (BT)-based 204
 - BSe- and Qx-based OSCs 209–210
 - BTA-based 201–204
 - features 200
- alkyl-aryl-based side chains engineering 189
- alkyl sulfide (WF₃S) 471
- all-polymer blend morphology control challenges 303
- all-polymer solar cells (all-PSCs) 275, 328, 415, 416
 - basics principles of 277, 278
 - device structures 277, 306
 - electron acceptor materials for 278
 - high-performance with small E_{loss} , BTI polymers for 287–289
 - molecular design strategy for BTI polymers 283–287

- all-polymer solar cells (all-PSCs) (*contd.*)
 for N2200 derivatives 279–283
 for PDI polymers 283
 morphology optimization and device
 engineering 303–307
 polymer acceptors bearing cyano
 groups 299–303
 stability enhancements 307
 ambient stability 308
 mechanical stability 308–309
 photostability 309–310
 thermal stability 307–308
- all-polymer system 275, 278, 305, 406,
 416
- alloy model mechanism 413
- alternating D1-A-D2-A terpolymers 18
- ambient light energy 456
- amine-functionalized fullerene (C₆₀-N)
 509
- amorphous silicon (a-Si) 455
- anode-cathode work function difference
 ($\delta\Phi_{AC}$) 488
- anode interlayer materials
 CPE 501–502
 cross-linkable polymers 502–504
 GO 504–505
 MO 505–506
 PEDOT
 PSS 496–501
- anode/organic interface 566, 567
- antiBTDC 83
- aperiodic sequence distribution 409
- appropriate charge extraction layer 558
- aromatic diimide-based conjugated
 polymers 275, 278–280
- atomic force microscopy (AFM) 13, 175,
 180, 260, 299, 362–364, 366–368,
 370, 372, 373, 424, 495, 521–524,
 541
- Auger electron spectroscopy (AES) 535
- Auger electron yield mode 495
- average visible-light transmittance (AVT)
 169, 179, 181, 268, 651, 654
- azafullerene derivatives 122
- azide-crosslinked fullerene interlayer
 (C-PCBN3) 509
- aziridine-flanked [2+1] monoadducts
 129
- b**
- back-reflector layer 650
- balanced crystallize rate 437
- ball-like geometry structure 529
- bandgap energy 148, 154, 157, 160,
 162, 170, 178, 185, 196, 203,
 591, 596
- band-to-band absorption 575
- batch-to-batch reproduction 417
- BD3T:PBN-14 based devices 330
- BDTT-*alt*-DTBTz 252
- benzo[1,2-*b*:4,5-*b'*]difuran derived
 polymers 28
- benzo[1,2-*b*:4,5-*b'*]dithieno[3,2-*b*]-
 thiophene (BDTT) building block
 176, 199
- benzo[1,2-*b*:4,5-*b'*]-dithiophene (BDT)
 249, 395
 based copolymers 216
 based NFAs 230
- benzo[1,2-*c*:4,5-*c'*]dithiophene-4,8-dione
 (BDD)-derived WBG polymers
 62, 253, 358, 473, 623
- benzo[*c*][1,2,5]thiadiazole (BT)-based
 A-DA'D-A type SMAs 204
- benzo[*c*][1,2,5]thiadiazole (FBF-N) 506
- benzodifuran (BDF)-based polymer 55
- benzodithiophene-*alt*-thiophene derived
 copolymers 46, 49–50
- benzodithiophene-based A–D–A-type
 molecular donors 90–95
- benzodithiophene-based D1-A-D2-A-D1-
 type molecular donors 101–103
- benzophenone (BP) 508
- 2,1,3-benzothiadiazole (BT)
 chemical structure of 3–4
 derived conjugated polymers
 optoelectronic properties and device
 performances 4–5

- quinoidal structure design concept 6
- benzothiadiazole-derived WBG copolymers 50–53
- benzothiophene with alkyl (WF_3) 471
- benzotriazole-based polymer donor (J52-F) 475
- benzotriazole-based WBG polymers 53–56
- bi-TPD based polymers 37
- bias-dependent charge collection 564–565
- bilayer MoO_3 /antimonene HEL 580–585
- bimolecular recombination coefficient 560–563
- bimolecular recombination lifetime 562, 563
- bimolecular recombination processes 558
- bimolecular recombination, in organic solar cells
 - bias-dependent charge collection 564–565
 - charge recombination process 560–563
 - metal oxide interlayer, on cell performance 557–560
- binary bulk-heterojunction (BHJ) system 472
- biomimetic electrodes 433
- bird droppings 649
- 2,3-bis(2-ethylhexyl)benzo[1,2-*b*:4,5-*c'*]-dithiophene-4,8-dione (TTDO) 64
- bisindigo-based polymers 13
- bisthiazole (BTz)-based polymer donor 58
- bisthiophenyl-benzo[*c*][1,2,5]thiadiazole (FTBTF-N) 506
- bithiophene imide (BTI) electron-accepting building block 315, 328
- blade-coated non-fullerene OSCs 437
- blade-coating 88, 415, 438, 544
- blended poly(ethylene glycol) (PEG) 494
- B←N bridged thienylthiazole (BNTT) 289, 292
- B←N unit for polymer acceptors
 - electron-deficient building blocks 289–292
 - E_{LUMO} optimization 292–294
 - enhancing electron mobility 295–297
 - optimizing active layer morphology 297–299
 - principle of 289, 292
 - tuning absorption spectra 294–295
- borondipyrrromethenes-based molecular donors 83–85
- bottom electrode 418, 420, 423–426, 429, 433, 434, 443, 446–448
- Bragg equation 526, 527
- bright-field (BF) imaging mode 524
- BSe-based OSCs 209–210
- BSS10-based All-PSC 283
- BT-derived MBG copolymers
 - alkoxyphenyl side chains 23, 24
 - alkylbenzothienyl side chains 24
 - alkylphenyl groups 23
 - oligothienyl sidechains 24
 - optoelectronic properties and device performances 23–26, 28–31
 - symmetry-breaking strategy 25
- BTA-based A-DA'D-A SMAs 201–204
- BTI fused ring oligomers 276
- BTI polymers, for high-performance all-PSCs with small E_{loss} 287
- BTIC-2Cl- γ CF₃-based semitransparent PSCs 268
- BTIC-BO-4Cl SMA, crystal structure of 267
- building-integrated OSCs
 - applications
 - OSCs-driven water splitting 666–668
 - OSCs-integrated glasses 668, 669
 - greenhouse and photosynthesis 652–655

- building-integrated OSCs (*contd.*)
 - OSC-integrated energy storage system
 - 661, 662
 - fiber-based OSCs-integrated ESS
 - 665–666
 - planar stacked OSCs-integrated ESS
 - 662–665
 - smart windows 650–651
 - solar parks 648–650
 - solar trees 651
 - wearable-integrated OSCs 655
 - implantable and wearable
 - self-powered sensors 656–658
 - OSC textile toward smart clothing
 - 658–661
 - portable device photovoltaics
 - 655–656
 - built-in potential on stability, of organic
 - solar cells 579, 580, 582, 583
 - interlayer modification 580–581
 - bulk heterojunction (BHJ) 436, 487, 556
 - active layer 519
 - cell 462
 - devices 415
 - films 406, 437
 - morphology 616
 - bulk transition metal dichalcogenides (TMD) 499
 - “burn-in” degradation 617
 - “burn-in loss,” 621, 623
 - button-sized battery 472
- C**
- carbon disulfide (CS₂) 92, 540–541
 - carbon nanotubes 419, 423–426, 432, 498, 504, 660–662
 - carbon-oxygen-bridged NFAs 233
 - carrier mobility 14, 49, 62–63, 165–167, 176, 218, 259–260, 262, 304, 306, 309–310, 355, 411, 413, 417, 479, 510, 512, 523, 540, 558, 560, 650
 - cathode buffer layer materials 509
 - cathode independent buffer layer 509
 - cathode interlayer materials 494
 - graphene derivatives, and other alternatives 512–513
 - organic small molecules 506–509
 - polymer cathode interlayer materials 510–512
 - cathode structures 563
 - cationic polymer interlayer C₆₀-ionene 509
 - C₆₀-based tandem solar cells 125
 - centrifugal force 436
 - charge accumulation 480, 564–565
 - charge carrier life time 609
 - charge collection, improvement and performance reproducibility 571
 - metal oxide interlayer, on cell performance 571–574
 - ZnO subgap states, suppression of 574–579
 - charge extraction layers 558
 - charge extraction process 489, 560
 - charge mobility 9, 47, 55, 156, 191, 253, 255, 267, 406–408, 411–413, 415, 540, 556–557, 560, 564, 579
 - charge transfer (CT) 556
 - complex 597, 609
 - mechanism 413
 - state 489
 - in OSCs 314
 - charge transport/recombination 566
 - chemical modification strategy, of BDT-BT-based polymers 22
 - chemical stability 22, 309, 355, 418, 513
 - chemical structures
 - of aromatic diimide-based conjugated polymers 280
 - of asymmetric cored FREAs 186
 - of block conjugated copolymers 346, 347
 - of BNTT, BNBP and BNIDT model compounds 292
 - of BTA-based A-DA'D-A type acceptors 202
 - of BT based SMAs 322
 - of BT/Qx/Bse-based A-DA'D-A type acceptors 206

- of double-cable polymers 356, 358–360
- of FREAs with space units 177
- of fullerene-based “in-chain” molecular dyads 337
- of fullerene-based “side-chain” D-A molecular dyads 340
- of IDTT-based FREAs 168
- of imide-functionalized arenes and heteroarenes 288
- of multiple fullerene-based “in-chain” molecular dyads 338
- of non-fused acceptors 195
- of P-BN-TPD and P-BN-IID 296
- of P-BNBP-T and P-BNBP-T 297
- of P-BNBP-T, P-BNBP-DPP 294
- of PBN-10 295
- of PDI dimers 149
- of PDI tetramers 156, 158
- of PDI trimers 153
- of polymer acceptors bearing cyano groups 301
- chemical vapor-deposited (CVD) graphene films 513
- chlorinated DIC-4Cl molecule 246
- chlorinated IDIC-4Cl 246
- chlorinated isoindigo (Cl-IIDT) 9, 245, 255
- chlorinated polymer donor (PM7) 242, 259, 262, 475
- chlorinated small molecular acceptors 262
 - crystal structure of 266–268
 - photovoltaic performance of 262–266
 - semitransparent organic solar cells based on 268–269
- chlorinated small molecular donors 260
- chlorination
 - on acceptor units of polymer donors 255–258
 - of π -Bridge of polymer donor 258–260
 - and “Same-A-Strategy” 254
 - of thiophene side chain 252
- chlorination of polymer donor units 249
 - in backbone 249–250
 - in side chain 250–255
- chlorination vs. fluorination 242
 - energy level and absorption, manipulation of 244–245
 - steric hindrance and morphology 245–246
 - synergistic effect of 246–249
 - synthesis of 242–244
- chlorobenzene (CB) 199, 323, 349, 437, 439, 441, 445, 448, 525, 542
 - solution 260, 567, 665
- C8-ITCC based devices 319
- clean energy 455
- cold isostatic-pressured (CIP) 430–431
- commercialization process 484
- common polymer substrates 418
- conjugated polyelectrolytes (CPEs) 490–491, 493, 501–502, 510, 571
- conjugated polymer donors with benzothiadiazole (BT) moiety 256
- conjugated polymer main chains 510
- conjugated polymer zwitterions 495
- “conjugated side chain” strategy 176, 296
- conjugated small molecules 410, 506, 520
- “contact arc” vaporization process 123
- copolymerization 3, 64, 96, 218, 222, 293–294, 296, 409–410, 631
- copper acetylacetonate precursor aqueous solution 506
- CPTCN derivatives 164, 166, 186, 192, 201
- cross-linkable polymer material 502–503
- cross-linkable polymers 502–503, 631
- crystalline conjugated polymers 413, 550
- crystalline domains 179, 277, 372, 528, 530, 635
- crystalline oligothiophene–diketopyrrolopyrrole 339
- crystalline polymer:fullerene 538
- crystalline silicon (c-Si) solar cells 455
- crystalline structure 58, 364, 528–529, 539–540

- C_{60} -TH-Hx 129
 CuO_x anode buffer layers 506
 current density (*J-V*) curve 593
 current density–voltage (*J-V*)
 characteristics 557
 cyclobutane-annulated fullerene acceptor
 FA4 129
 cyclopentadiene 167, 169, 174, 192–193
- d**
- D-A-A'-type SMDs 78, 80, 83, 84, 125
 D1-A-D2-A-D1-type molecular donors, in
 SP-SMSCs 96
 benzodithiophene-based 101–103
 dithienosilole-based 99–101
 indacenodithiophene-based 103–105
 dark ball-like domain 524
 dark current 523, 564, 566, 592, 594
 dark current density 593
 dark saturation current 593, 595
 DBP-based BHJ device 88
 DBTTC:PBDB-T blend film 230
 2D charge-coupled device (CCD) 526
 DC-IDT2T 176–178, 224–225
 DCNBT-IDT narrow-bandgap polymer
 acceptor 299–300
 DCV5T-Bu_{2,2,4,4} 79–80, 89
 DCVnTs-Bu-based devices 79
 Debye–Anderson–Brumberger (DAB)
 model 531–532
 Debye–Bueche model 532
 Debye–Scherrer-like ring 528–529
 degradation mechanisms 556, 579–580,
 585, 613–614
 delay time dependent bimolecular
 recombination equation 562–563
 delay time dependent density, of electrons
 562
 depth profile 534–537, 550, 551
 device efficiency of PDI-based acceptors
 149, 158
 device fabrication 286, 298, 305, 309,
 331, 383, 401, 405, 417, 434–445,
 488, 493–494, 578
 2,6-diaminopyridine tethered fullerene
 derivative (PCBP) 627
 diaryl-substituted methanofullerenes
 129
 3,4-dicyanothiophene (DCT) 49
 [2+4] Diels–Alder cycloaddition 130
 different delay time dependent 561–562
 1-8-diiodooctane (DIO) 163, 173, 183,
 305, 437, 534, 543–547, 614, 621,
 624
 diisoidigo-containing polymers 13
 diketopyrrolopyrrole (DPP)-based
 polymer 628
 chemical structures 14, 15
 optoelectronic properties and device
 performances 17, 21
 with different flanking units 15
 3-dimensional charge transfer channel
 406
N,N-dimethyl formamide (DMF) 498
 dimethyl 2,2'-(thieno[3,2-*b*]thiophene-
 2,5-diyl)bis(thiophene-3-
 carboxylate) (4T2C) 409
 dimethyl sulfoxide (DMSO) 419, 423,
 443, 498
 dipole orientation 491, 495, 513
 dispersion parameter 562–563
 dithieno[2,3-*d*:2',3'-*d'*]benzo[1,2-*b*:4,5-*b'*]
 dithiophene (DTBDT) 64, 94,
 111, 328
 dithieno[2,3-*d*:2',3'-*d'*]benzo[1,2-*b*:4,5-*b'*]
 dithiophene (DBD) 43
 dithieno[3,2-*b*:2',3'-*d*]pyran (DTPR) 174
 dithienocarbazole (DTC) 219
 dithienocyclopentadibenzothiophene
 (DTCD) 221–222, 230
 dithienosilole-based A–D–A-type
 molecular donors 95–96
 dithienosilole-based D1-A-D2-A-D1-type
 molecular donors 99–101
 3D nanoscale polymer network 524
 domain purity 94, 111, 156, 208, 298,
 415, 519–520, 526, 533–534, 543,
 545, 551
 donor-acceptor (D–A) 408

- active layer 488
- combined π -bridge 324
- interface 489, 556, 597
- phase separation 616
- type copolymers construction 2
- dopamine hydrochloride (DA·HCl) 500
- double fluorine substituted INCN 165
- double-cable conjugated polymers, for SCOSCs 350–361
- double-cable polymers 350–351, 353–361, 367–368, 372, 375, 627–628
 - based SCOSCs 368
- double-cable single-component photoactive layers 631
- downshifting HOMO energy level 411
- DPP(TBFu)₂ 108
- DPPZnP-THE porphyrin derivative molecule 393
- DR3TBDTC:PBN-11 based devices 330
- drift current 566–569
- driving energy (ΔE_{CT}) 597
- 3D-surfactant-based graphene composites 513
- DTCC-based NFAs 229
- DTDCTB 80, 82
- DTNIC8 225–226
- DTNR-based device 226
- DTPC-DFIC-based PSC 229
- DTTC-4Cl:PM6 blend film 235
- dye-sensitized solar cells (DSSCs) 455, 617
- e**
- eco-friendly R2R manufacturing 647
- “edge-on” crystalline structure 529
- “effective” bimolecular recombination lifetime 563
- effective medium approximation (EMA) 537
- efficiency loss, in large-area devices and modules
 - additional losses 448
 - electrical losses 446–447
 - geometric losses 447
 - modular designs 448
 - optical losses 448
- efficient charge extraction 383, 397, 489, 509, 558, 581
- efficient charge transport 34, 172, 173, 177, 181, 184, 209, 218, 219, 360, 408, 411, 519, 564, 575, 645
- efficient photo-to-electricity conversion processes 617
- eight-ring fused isoindigo-based acceptor unit thieno[3,2-*b*][1]benzothio-*phene* isoindigo (TBTI) 13
- Einstein coefficient 603
- electric field re-distribution 560
- electrochemical polymerization (ECP) 350, 356
- electroluminescence spectrum 607
- electromagnetic radiation 458, 459
- electron affinity (EA) 4, 78, 86, 122, 200, 278, 283, 322, 410, 473
- electron cutoff (E_{SEC}) 495
- electron injection 509, 523
- electron microscopy techniques 521, 524
- electron transporting layers (ETLs) 442, 443, 478, 479, 493, 512, 661
- electron-acceptor 519, 523
- electron-blocking ability 503
- electron-donor 519, 550
- electron-hole pairs 277, 278, 591, 596, 665
- electron-withdrawing ability, of INCN 160, 164, 166
- electron-withdrawing end moieties 586
- electronic and photovoltaic performance of polymer donors based chlorinated π -bridge 258–259
 - of polymer donors based chlorinated backbone of A unit 255, 257
 - of small molecule acceptors based chlorinated IC end groups 262, 264
- ellipsometry 537
- embodied energy 648, 649
- emission power spectrum 460

- emitted photons 603
 - endohedral fullerenes 121, 122, 138
 - energetic offset 597, 600, 604, 606
 - energy dispersive X-ray spectroscopy (EDS) 535
 - energy distribution, for OPV cells 480, 481
 - energy levels
 - for A–D–A type NF SMAs 169–170
 - for A–D–A type non-fullerene SMAs 176, 178
 - with asymmetric structures 184–185
 - with non-fused cores 194, 196
 - for A–D–A-type SMAs 160, 162
 - for A-DA'D-A type non-fullerene SMAs 201, 203
 - for BT based NFAs 322–323
 - for BTA based NFAs 326
 - for PDI monomer-and dimer-based NF-SMAs 148
 - for PDI tetramer-based NF-SMA 154, 157
 - for PDI trimer-based NF-SMAs 154
 - energy of bandgap 591
 - energy pay-back time (EPBT) 648, 649
 - energy transfer mechanism 413
 - energy-harvesting systems 646
 - environmental pollution 455
 - environmentally friendly solvents 437, 440
 - e*-PPMF isomer-free bisadduct 134
 - ethylene glycol (EG) 498
 - 3-ethylrhodanine (RD) 89, 226, 323, 324, 330
 - exciton blocker 508
 - exciton dissociation 3, 13–15, 47, 60, 77, 78, 86, 96, 110, 123, 146, 162, 182, 183, 191, 198, 225, 277, 300, 357, 361, 370, 375, 415, 480, 494, 497, 512, 519, 538, 542, 543, 545, 557, 558, 564, 565–571, 573, 576, 577, 582, 587
 - exciton dissociation efficiency 361, 542, 543, 545
 - exponential term dependent 593
 - external quantum efficiency (EQE) 4, 85, 138, 247, 278, 339, 391, 461, 557, 580, 594, 595, 638, 667
 - of all-PSCs 278
 - extraction current maximum 560
- f**
- FA-based material systems 625
 - fabricated photovoltaic devices 472
 - “face-on” molecular order 529
 - face photo-oxidation process 614
 - face-on molecular orientation 232, 530, 540, 542, 550
 - face-on molecular packing 529, 530
 - face-on orientation 4, 13, 105, 112, 169, 179, 186, 187, 190, 198, 232, 237, 245, 282, 357, 367, 368, 409–412, 414, 415, 417
 - F-BTA3-based devices 328
 - 2F-DRCN5T 317
 - feedback loop 521
 - few-layered graphene quantum dots (F-GQDs) 504
 - ff2T-based PT derivative 47
 - fill factor (FF) 3, 79, 131, 313, 384, 409, 460, 488, 558, 591, 606, 615
 - of photovoltaic devices 313
 - film density 436, 438
 - film formation 78, 196, 198, 305, 440, 500, 501, 510, 551, 631
 - film morphology 39, 52, 78, 153, 182, 252, 284, 286, 309, 324, 329, 408, 410, 417, 436, 439, 442, 494, 498
 - film thickness 163, 193, 306, 384, 393, 410, 411, 413, 415, 436–438, 440, 441, 443, 504
 - film-coating process 542
 - film-forming process 297, 519, 545, 546, 549–551
 - film-processing methods 520
 - film-state packing 409
 - fitted parameters 563

- “flat-on” molecular order 529
 flat-on molecular orientation 530, 551
 flexible electrode 405, 417–434, 443, 448, 449
 flexible substrates 1, 405, 418–419, 420, 423, 425, 435, 439, 616
 flexible transparent bottom electrodes (FTBEs) 419–420
 flexible wearable devices 456
 flexural strain 434
 Flory–Huggins interaction parameters 348
 fluorescent lamps (FL) 295, 456
 fluorescent lamp illumination 473
 fluorinated BTI monomers f-FBTI2-Br 286
 fluorinated dibenzo[*a,c*]phenazine acceptor units 35
 fluorinated IDIC-4F 246
 fluorinated monomers f-FBTI2-Br 287
 fluorination 4, 9, 22, 34, 37, 42, 47, 49, 54, 55, 63, 88, 90, 225, 229, 234, 241, 246–249, 254, 255, 258, 262, 266, 269, 270, 284, 287, 316, 321, 482, 549, 623
 fluoropolymer polymers 546
 fluorothiophene (WF₃F) 321, 344, 471
 fractal aggregation model 532
 fractal-like aggregations 532
 Frank-Condon weighted density of states (FCWD) 601, 602
 free-halogen solvents 448
 free-radical reaction 585
 FTAZ:IDCIC blend film 235
 FTAZ:INIC2 based OSCs 167
 fullerenes (C₆₀) 121
 [2+*n*] cycloadditions 121–122
 endohedral fullerenes 121, 122, 138
 fullerene acceptors 410
 molecular structure 316
 in tandem OSCs 384–393
 fullerene acceptors for OSCs
 monoadduct acceptors 126
 [2+1] addition derivatives 126–129
 [2+2] addition derivatives 129
 [2+3] addition derivatives 129–130
 [2+4] addition derivatives 130
 1,4-addition derivatives 130
 performance 126, 128
 representations 126, 127
 pristine fullerenes 123–126
 fullerene-based “in-chain” molecular dyads 336–339
 fullerene based SMAs 315–317
 fullerene-based “side-chain” D-A molecular dyads 339–341, 362
 fullerene-based binary system 406–410
 fullerene-based OSCs
 energy levels and device characteristics 316
 fullerene-based SMSCs 78, 107, 110, 115
 fullerene bisadduct acceptors 130–132, 135
 fullerene dimerization 617
 fullerene multiadduct acceptors 135, 136
 fullerene systems 411, 546
 fused PDI-V-based polymer NDP-V 283
 fused pentacyclic aromatic lactam building block 65
 fused ring moieties 410
 fused-ring electron acceptors (FREAs) 111, 167–169, 171–174, 176, 177, 184, 186–194, 335, 621
 fused-ring non-fullerene acceptor 645
 fused-ring PDI dimers 150, 152
 fusion quenching sol-gel method 505
- g**
 gas discharge 458
 gasochromic tungsten trioxide/platinum (WO₃/Pt) 650
 generalized Mulliken–Hush (GMH) method 603
 geometric fill factor (GFF) 437, 445, 447, 448
 geometric patterns 445
 glass substrates 277, 406, 419, 423, 439, 482, 567, 571, 577, 616, 669
 global warming potential (GWP) 648–649

- graphene oxide (GO) 426–428, 488, 504–505, 512
- graphene-fullerene composite (rGO-pyrene-PCBM) 512
- gravure printing method 443
- grazing incidence geometry 527
- grazing incidence small angle neutron scattering (GISANS) 533–534
- grazing incidence small angle X-ray scattering (GISAXS) 357, 368, 370, 530–533, 545, 551
- grazing incidence wide angle X-ray scattering (GIWAXS) 52, 157–158, 184, 199, 297–299, 357, 363–364, 367–368, 370, 372–374, 527–530, 539, 541, 543, 545–546, 548, 550, 624
- h**
- halogen lamps 456
- halogen-substituted INCN 165
- halogenated (chlorobenzene (CB)) 439
- Hansen solubility parameters (HSP) 544
- harmonic oscillators 605
- 5H-dithieno[3,2-*b*:2',3'-*d*]pyran-5-one fused building block 65
- heating-induced degradation 615
- heptacene-based D–A copolymers 219–222
- heptacyclic benzodi(cyclopentadi-thiophene) (BDCPDT) building block 222, 230, 395
- 2,2,3,3,4,4,4-Heptafluoro-*N*-phenyl-butyr-*amide* (F-ADD) 547
- heteroacenes based D–A copolymers, with 9 or more fused rings 222–223
- hexacyclic heteroacenes-based D–A copolymers 217–219
- hexakis(fluoren-2-yl)benzene (HFB) (T1-OH) 508
- high charge mobility 267, 407, 412
- high charge recombination 406, 581
- high corrosion resistance 418
- high-frequency vibration modes 601
- high-performance all-PSCs with small E_{loss} , BTI polymers for 287–289
- high-power conversion efficiency (PCE) 419
- high-viscosity polymers 415
- high-voltage fullerene-based OSCs 316
- high-voltage OSCs 315
design rules for 330
- higher fullerenes 121, 122, 138, 139
- highest occupied molecular orbital (HOMO)
downshifting HOMO energy level 37, 62, 108, 205, 411
upshifted HOMO level 36, 89–90, 172, 179, 181, 411
- highest occupied molecular orbital of donor (HOMO_D) 489
- hole injection 493
- hole transporting layers (HTL) 277, 397–398, 496–497, 499–505, 556, 651, 660
- hole-transporting characteristics 503
- homo-tandem cells based on PTB7-Th:PC₇₁BM active layer 391
- homogeneous fibril-like bicontinuous interpenetrating network 409
- horizontal q_{xy} (in-plane) 528
- hot substrate 86, 437, 550–551
- H-tri-PDI 150
- hybrid films 419, 432–434
- hydrocarbon solvents (1,2,4-trimethylbenzene (TMB)) 439
- hydrogen evolution reaction (HER) 666
- hydrogen fuel cell automobile 651
- hydroiodic acid (HI) 428
- i**
- ideal Shockley–Quessier solar cell 593
- ideal solar cell 591–594
- identical anode/organic contact 565
- IDIC 52, 59, 63, 111, 163, 246, 321
- IDT-3MT SMA 181
- IDT-based SMA 319
- IDT-BOC6 SMA 183, 319

- IDT-OB 163, 193, 412
 IDTCPDT-based copolymer 222
 illuminance of, light source 460
 incident angle 527, 533, 661
 incident light power 460
 incident photon to current efficiency
 (IPCE) 557, 572, 573
 indacenodithieno[3,2-*b*]thiophene (IDTT)
 6, 160, 216, 319, 322
 indacenodithieno[3,2-*b*]thiophene-based
 ladder-type polymer 29
 indacenodithiophene (IDT)-based
 D1-A-D2-A-D1-type molecular
 donors 103–105
 indacenodithiophene-based D-A
 copolymer 218
 indene C₆₀ trisadduct (IC₆₀TA) 135
 indene-C₆₀ bisadduct (ICBA) 46–47,
 133, 406, 415, 471
 indenothiophene-based copolymer
 (PITFBT) 219
 indium tin oxide (ITO) 277, 339, 409,
 419–420, 423–424, 427–434, 446,
 448, 473, 477–478, 481, 495–498,
 500–501, 503, 505–507, 509–510,
 556, 567, 571, 573, 579, 616, 653
 indoor ambient lighting sources 456
 indoor light recycling applications 331
 indoor lighting 456
 conditions 462
 sources 457
 indoor photovoltaic (IPV) cells 294, 315,
 456, 461
 inevitable initial oxidation 556
 initial carrier density 562
 ink concentration 436, 438, 440–441, 443
 inkjet printing technology 440, 441
 inorganic or organic/inorganic hybrid
 perovskite solar cells 591
 inorganic or perovskite solar cells 591,
 596
in situ photoelectron spectroscopy 557
 inter-chain stacking 406
 inter-contact (R_{int}) resistance 446
 interconnect resistance (R_{int}) 447
 interfacial design, mechanism and effect
 of
 BHJ morphology and device stability
 494
 doping effect, on energy level
 alignment 492–494
 electrode work function difference, role
 of 488–489
 interaction b/w, metal electrode and
 interlayers 490–492
 interfacial morphology
 characterizations 495–496
 interfacial dipole (Δ) 490–492, 495,
 504–505, 510
 interfacial doping approach 492, 493
 interfacial exciton dissociation 557,
 564–570, 573, 577, 587
 interior lighting 459
 internal electric field 305, 488, 566,
 568–570, 581–582
 internal quantum efficiency (IQE) 123,
 150, 283, 318, 357, 375, 594,
 606–607
 internal resistance (R_i) 446, 448, 504
 International Summits on Organic PV
 Stability (ISOS) 617
 internet of things (IoTs) 294, 315, 335,
 456, 458, 483–484, 646, 655, 658
 intramolecular charge transfer 3, 79,
 200, 229, 241, 356, 586
 intramolecular heterojunction 336, 362
 inverted or reverse configuration OSCs
 556
 ionic chain reorientation 490
 IPT2F-TCl asymmetric FREA 191
 irradiance spatial non-uniformity 460
 irradiation spectra, of LEDs 462
 isoindigo-based conjugated polymers
 heteroatomic substitution 9
 optoelectronic properties and device
 performances 9, 11, 13
 structural modification 9
 isoindigo-containing polymers 13
 isomer-free bisadduct 134, 139

- isomeric DTN-based copolymers
 - (PDTNTBT and PaDTNTBTO) 219
 - isomeric IDTT-based acceptors 321
 - isomerization strategy 156
 - ITIC5-based blend film 230
 - ITO-coated polyethylene naphthalate (PEN) substrates 665
 - ITOIC-2Cl SMA 182
 - ITO/PEDOT:PSS/Polymer/Al polymer-based SCOSCs 357
- j**
- J71:IT-DM-based device 322
 - J71:ITCNTC OSCs 192
- k**
- K-shell absorption edges 495
- l**
- lab-to-manufacturing translation 651
 - L14 acceptor-acceptor type polymer acceptor 303
 - ladder-type heteroacenes 215–237
 - ladder-type nonacyclic thienyl-phenylene-thienylene-phenylene-thienyl (TPPT) building block 222
 - ladder-type pentacyclic heteroacene 218
 - Laguerre polynomial 602
 - large energy loss (E_{loss}) 21, 313
 - large-area flexible device fabrication 434
 - coating and printing methods 435–443
 - blade coating 436–438
 - gravure printing method 442–443
 - inkjet printing 440–441
 - relief printing method 443
 - screen printing 442–443
 - slot-die coating 438–439
 - spray coating 441–442
 - R2R methodology 443–445
 - large-area flexible electrode 443, 448
 - large-area flexible organic solar cells
 - flexible substrates 418–419
 - FTBE 419
 - carbon nanotubes 423–426
 - conducting polymers 419–422
 - graphene 426–429
 - hybrid films 432–434
 - metallic nanowires 429–432
 - material requirements 406–417
 - all-polymer-based system 415–416
 - design strategies 417
 - fullerene-based binary system 406–410
 - nonfullerene-based binary system 410–413
 - ternary system 413–415
 - large-range tunability 645, 647, 650
 - large-scale printing technology 647
 - layer-to-layer depth profiling 535
 - leaf-like biomimetic electrodes (PPZA) 433, 434
 - leakage current 458, 477, 478, 480, 483, 559, 576, 580
 - levelized cost of energy (LCOE) 613
 - life cycle analysis (LCA) 648, 649
 - light effect 614–615
 - light emitting diode (LED) 78, 146, 295, 315, 432, 456, 493, 555, 628, 656, 659
 - radiative spectrum 473
 - light illumination 350, 399, 421, 462, 522, 585, 629, 632, 665
 - light intensity 315, 456, 460, 461, 473, 475, 477, 478, 480, 484, 500, 557, 559, 564, 574, 579, 661
 - light intensity-dependent J - V characteristics 557
 - light-emitting diodes (OLED) displays 78, 146, 295, 315, 432, 456, 493, 555, 656, 659
 - light-induced degradation 614
 - linear shaped naphtho[2,3-*b*:6,7-*b'*]dithiophene (NDT) 44, 64, 94, 111, 173
 - π -linker 89, 94, 96, 105, 114
 - liquid crystalline small molecule donor
 - BTR 415

- liquid droplet 441
- local excited (LE) states 597
- low bandgap (LBG) polymers 1
 - based on 2,1,3-benzothiadiazole 3–8
 - based on diketopyrrolopyrrole 14–19
 - based on isoindigo 8–14
- low bandgap photoactive organic semiconductors 555
- low bimolecular recombination 411, 417
- low charge mobility 406, 557
- low electron mobility, of fullerene bisadducts 112, 133, 135, 295
- low frequency reorganization energies 601, 603
- low molecular weight fraction (LMWF) 522, 523
- low-power indoor electronic device 456, 457
- lower series resistance/ parallel resistance (R_s/R_p) ratio 480
- lowest unoccupied molecular orbital (LUMO) levels 122, 129, 133, 462, 597
 - fulleropyrrolidine acceptors 129
 - of IC₆₀MA 130
 - C₈₀-PCBH 138
 - OQThC₅₉N 137
- lowest unoccupied molecular orbital of acceptor (LUMO_A) 489
- luminescence principles 458
- m**
- magnitude of, built-in electrostatic field (V_{bi}) 488
- maximum current density (J_{sc}) 488
- medium bandgap (MBG) polymers 1
 - based on 2,1,3-benzothiadiazole 22–31
 - based on quinoxaline 31–35
 - based on thieno[3,4-b]thiophene 40–45
 - based on thieno[3,4-c]pyrrole-4,6-dione 35–40
- MEH-PPV:PC61BM solar cells 123
- merocyanines (MCs) 86, 125
- “M-series” low bandgap NFAs 231
- meso-erythritol 498
- metal foil substrate 418
- metal oxides (MOs) 505–506
- metal/organic interfacial exciton dissociation 565–566
 - charge collection, in regular configuration organic solar cells 566–569
 - charge collection, inverted organic solar cells 569–570
- metallic nanowires 429–432
- methano-PC₆₁BM 133
- methanofullerene derivative PC₆₁BM 126
- methyl-substituted end group 164
- 2-methyltetrahydrofuran 415
- micro-cavity effect 478
- micro-phase separation 361, 364, 367, 621
- microscopic method 521–526
- microscopic phase separation, in SCOSCs 364
- microscopic techniques 521, 526
- modern organic solar cells (OSCs) 519
- molecular design strategy
 - for BTI polymers 283–287
 - for N2200 derivatives 279–283
 - for PDI polymers 283
- molecular dyads, SCOSCs
 - fullerene-based “in-chain” molecular dyads 336–339
 - fullerene-based “side-chain” D-A molecular dyads 339–341
 - PBI-based 341–344
- molecular structure
 - of BTA and Qx based NFAs 325
 - of BTR and BTR-Cl 261
 - of fullerene acceptors 316
 - of naphthalene diimide (NDI) polymers 275
 - of PDI based NFAs 317
 - of polymer donor PTB7-Th 290
 - of polymers acceptors 329
 - of SMAs containing IC units 320

- molybdenum oxide nanoparticle layer
(MoO₃) 99, 425, 499–500, 505, 580
- monomeric PDIs 146–147
chemical structure 147
- monomolecular recombination 489, 558
- MoO₃/antimonene layers 580
- morphological manipulation of, organic solar cells
solid additive 547, 549
solvent 542–544
solvent additive 544–547
substrate effect 549–551
SVA 540–542
thermal annealing 538–540
- morphological studies, SCOSCs
block copolymers 366–367
double-cable polymer-based SCOSCs 367–375
molecular dyads 362–366
- Mott–Gurney law 523
- multi-junction solar cells 594
- multiple monolithic inter-connecting cells 448
- multiple trapping model 562
- multiwalled carbon nanotube (MWCNT) fiber 498–499, 661, 665
- n**
- N*-alkylaziridino[60]fullerene (NNAF) acceptors 129
- N*-cyclized *s*-diPBI (*N*-PDI) 149
- n*-doped fulleropyrrolidinium iodide (FPI) 508
- n*-doped graphene-PDINO composite (PDINO-G) interlayer 513
- N*-heterocycles-based acceptor building blocks 56
- N*-heterocyclic benzene derivatives 60
- n*-type perylene diimide (PDI) 111, 146, 275, 315, 324, 472, 478, 493, 506
- n*-type polymers 275, 328–330
- n*-type small molecule acceptors
fullerene based SMAs 315–317
non-fullerene SMAs 317–328
- n*-type terpolymers BTI2-xTPD 328
- n*-type water/alcohol-soluble conjugated polymers (WSCPs) 493, 510, 512
- N2200-based terpolymer PNDI-Si25 283
- nanophase separation 370
block copolymers 366–367
of double-cable polymers 368
- nanoscale morphology 349, 519–521, 526, 543, 629, 631
- naphthalene diimide (NDI) 275, 278, 279, 282–284, 289, 292, 305, 309, 310, 348, 349, 350, 355, 357, 361, 372, 493, 506, 512
- polymers
crystallinity of 282
synthesis 279
- naphthalene-based NFA (PDT-T) 226
- naphthalenothiophene imide (NTI)-based copolymer 68
- naphtho[1,2-*c*:5,6-*c'*]bis[1,2,5]thiadiazole (NT)-derived conjugated polymers 4
optoelectronic properties and device performances 6
- naphthodithiophene (NDT) 44, 64, 94, 111, 173
- narrow bandgap 6, 150, 160, 229, 279, 289, 299, 300, 302, 303, 324, 349, 357, 358, 384, 408, 410, 457, 462, 633, 658
- narrow band gap photoactive materials 457
- near edge x-ray absorption fine structure (NEXAFS) measurements 495, 496, 535, 536
- near-infrared light (near-IR) 410, 658
- net-like structured conductive channels 498
- neutral phosphonate pendent chains 506
- neutral surface modifiers 510
- neutron reflectivity (NR) techniques 536
- new-type transparent bottom electrodes 433

- 1-*n*-hexylisoorotic acid moieties 627
- nickel (Ni)-coated polyester yarn 666
- nickel oxide (NiO) thin films 506
- n*BuBTDC-based device 83
- 2-nitroethanol 498
- nitrogen-bridged small molecule acceptors 236
- nitrogen-containing heterofullerenes 121
- NOC6F-2-based OSCs 199
- non-conjugated polyelectrolytes 510
- non-fullerene acceptors (NFAs) 417, 530, 547, 618
- based tandem OSCs 393
- non-fullerene electron acceptors 645
- non-fullerene films 530
- non-fullerene small molecule acceptors (NF-SMAs) 110
- A₂-A₁-D-A₁-A₂ type SMAs
- with benzothiadiazole 322
- with benzotriazole 325–328
- with quinoxaline 328
- A–D–A-type SMAs 160–200
- IC and derivatives based A–D–A type SMAs 319–322
- molecular design principles 145–146
- PDI-based 317–319
- PDI-based SMAs 146–160
- PDI tetramers 153–160
- PDI trimers 150–153
- non-fused cores, in ADA-type SMAs 167, 194–200
- non-fused-ring acceptor (NFRA) 194, 198, 199
- non-halogenated solvent 410, 439, 635
- non-radiative recombination rate 172, 197, 198, 205, 208, 314, 318, 319, 327, 328, 330, 595, 596, 606, 609
- non-radiative recombination voltage loss 595, 606, 609
- non-radiative relaxation process 575
- non-radiative voltage loss 317, 601, 606
- non-uniform charge distribution 562
- nonacyclic DTCC-based NFA (CZTT) 234
- nonfullerene acceptors (NFAs) 78, 110, 139, 215, 317, 322, 323, 326, 384, 242, 260, 262, 265, 317, 322, 323, 325, 326, 383, 384, 393, 394, 400, 410, 585, 615, 618, 623, 624, 627, 639
- nonfullerene-based binary system 406, 410–413
- nonradiative Förster resonance energy transfer 414
- nonradiative loss 599
- n*-PV-fullerene dyads, for SCOSCs 337
- O**
- O-BDTdFBT-based blend 108
- octacyclic heteroacene based on naphtho[1,2-*b*:5,6-*b'*]dithiophene 235
- Ohmic contact 383, 397, 433, 447, 477, 493, 497, 509, 558
- oligomer-like small molecules 317
- oligothiophene-based A–D–A-type molecular donors 89
- oligothiophene-based small molecule donor materials 79, 80
- molecular structures 81
- performance 82
- oligothiophene segment 633
- opaque metal/organic cathode interface 566
- open-cage fullerenes 136–137, 139
- open-circuit voltage (V_{oc}) 460, 488
- of non-fullerene-based OSCs 314
- of photovoltaic devices 313
- optical bandgap
- for A–D–A type NF SMAs 170
- for A–D–A type non-fullerene SMAs 178
- with asymmetric structures 185
- with non-fused cores 196
- for A–D–A-type SMAs 162
- for A-DA'D-A type non-fullerene SMAs 203
- for PDI monomer-and dimer-based NF-SMAs 148

- optical bandgap (*contd.*)
 - for PDI tetramer-based NF-SMA 157
 - for PDI trimer-based NF-SMAs 154
- optical microscopes 521
- optical semitransparency 650
- optical transitions 597, 604
- π - π ordering 529
- organic boron chemistry 276
- organic/cathode interface 556–557, 565–567, 572–573, 587
- organic electronic devices 492–493, 510
- organic electronic technology 555
- organic light-emitting diodes (OLEDs) 493
 - based flat panel displays 555
 - solid-state lighting 555
- organic materials 179, 305–306, 381, 458, 530, 564, 570, 604–606, 614, 645
- organic photovoltaics (OPV) 613
 - energy collection modules 456
 - technology 241, 557
- organic photovoltaics, for indoor applications
 - indoor lighting sources, characteristics of 458–460
 - research progresses 461–462
 - fullerene based OPVs 462–472
 - interface engineering of OPVs 476–479
 - large-area OPVs 480–483
 - multiple blend OPVs 474–476
 - non-fullerene based OPVs 472–474
 - thick film OPVs 479–480
 - testing system and parameters 460–461
- organic semiconductors 146, 201, 242, 245, 262, 270, 277, 313, 381, 479, 487, 492–493, 510, 513, 519, 524, 526, 533, 555–556, 585, 595, 605, 645–648, 650
- organic solar cells (OSCs) 405, 455, 487, 555, 591
 - advantages 77
 - development of, organic photovoltaic materials 618–621
 - on fullerene acceptors 621–623
 - non-fullerene acceptors 623–624
 - on polymeric acceptors 625
 - factors limiting, stability of 614
 - environmental effect 615
 - extrinsic stresses 614–615
 - intrinsic factors 616–617
 - mechanical stress effect 615–616
 - stability evaluation protocols 617, 618, 620
 - thermal effect 615
 - morphological characterization of microscopic methods 521, 523, 524
 - power conversion efficiency 241
 - strategies, morphological stability of 625, 627
 - cross-linking 629–631
 - developing with, excellent stability 635, 637–639
 - donor and acceptor as,
 - single-component photoactive layer 627–629
 - hydrogen bonding, in photo-active materials 627, 628
 - organic nanoparticles 633
 - solid additives 631, 632
 - solvent additives 631–633
 - stratified photoactive layer structure 633, 635, 636
 - ternary and multiple composites 633, 634
- organic-semiconductor films 524, 526
- organic/cathode interfaces 556–557, 565–567, 572–573, 587
- (organo)-(hydro)[60]fullerenes 130
- ortho-xylene (o-XY) 439
- orthodichlorobenzene (oDCB) 441
- OSC-biased water splitting 667
- OSC-integrated energy storage systems 661
- α -OT 80
- oxidative polymerization, of ethylenedioxythiophene 496

- 2-(3-oxo-2,3-dihydro-1*H*-inden-1-ylidene)malononitrile (INCN) 160, 164
- 2-(3-oxo-2,3-dihydroinden-1-ylidene)malononitrile (INCN) moieties 224, 580
- 2-(6-oxo-5,6-dihydro-4*H*-cyclopenta[*c*]-thiophen-4-ylidene)malononitrile (CPTCN) 164, 186, 230
- oxygen evolution process (OER) 666–668
- o*-xylylene C₆₀ trisadduct (OXCTA) 135
- ozone molecules 505
- q**
- quasi-amorphous structural properties 478
- quasi-Fermi level 489
- quasi-Fermi level splitting 594
- quaternary ammonium bromide pendant groups 506
- quaternary BHJ (Q-BHJ) device 475
- quinoxaline-derived copolymers
chemical structure 32
optoelectronic properties and device performances 32, 35, 36
- quinoxalino[6,5-*f*]quinoxaline (NQx) 35
- Qx-based OSCs 209–210
- p**
- parallel linkage mechanism 413
- PBDB-T:a-BTTIC based OSCs 192
- PBDB-T:DOC2C6-IC based OSCs 198
- PBDB-T:DTNIC8 blend, hole and electron mobilities for 226
- PBDB-T:DTPPSe-2F based devices 189
- PBDB-T:IDT-EDOT based OSCs 183
- PBDB-T:IDT6CN-Th based device 193
- PBDB-T:IDTO-T-4F based device 184
- PBDB-T:IPT2F-TCl based OSCs 191
- PBDB-T-2Cl polymers 207, 242, 243, 244, 253, 254
- PBDB-T-SF:IT-4F-based OSCs 165, 411, 439, 668
- PBDB-TF polymers 242–243
- PBDB-TF:ITZN-C9-based devices 321
- PBDT-ODZ:ITIC-Th devices 321
- PBFSF ternary conjugated polymer 306
- PBI-based double-cable polymers 358
- PBI-based molecular dyads 341–344
- PBPD-Th:ITIC based PSC 319
- PBQx-TCl:BTA₃-based device 327
- PBT1-C:TPTTT-2F based OSCs 186
- PBT1-C:TPTTT-4F based OSCs 192
- PBT1-EH:ITCPTC-based OSCs 166
- PBT4T-Cl based devices, hole and electron mobility of 250
- PBT4T-Cl polymer donor 250
- PC₇₀BM molecules 524, 532
- PC₇₁BM surface 567
- PCBM-like fullerene acceptors 126
- PCBT4T-2BO polymer 248
- PCBT4T-2OD polymer 248
- PDI polymer acceptor (PDI-TT) 283
- PDI-based ionene polymer interlayers 493
- PDI-based SMAs 146–160, 317–319
- PE62:F-Qx3b-based device 328
- PEDOT quinoidal nanostructures 586
- pendant perylene bisimide (PBI) 155, 336, 341, 343, 344, 345, 348, 350, 355, 356, 357, 358, 360, 361, 362, 364, 365, 370, 372, 628
- pentacyclic heteroacenes-based D-A copolymers 217–219
- permittivity of, free space 523, 602
- perovskite solar cells (PSCs) 146, 289, 313, 381, 455, 493, 591, 596, 607, 617, 647
- perylene diimide (PDI)-based SMAs 146
functionalization positions on PDI 146, 147
monomeric PDIs 146–147
PDI dimers 147–150
- perylene diimide (PDI)-based SMSCs 111, 146, 275, 315, 324, 472, 478, 493, 508
- PFBDT-IDTIC polymer acceptor 63, 300
- Ph₂-benz-BODIPY 83

- phase separation 362
 - of double-cable polymers 357, 368
- phenothiazine trimer backbones 506
- phenyl-terminated isoindigo polymers 13
- phosphomolybdic acid (PMA) 397, 493
- photoactive layers, of OSCs 417, 475, 494, 500, 566, 615, 631, 645, 647
- photoactive layer thickness 480, 481
- photochemical degradation 614, 615
- photochemical method 505
- photocurrent density 564, 593
- photo-degradation process 615
- photo excitation 558, 560
- photo-excited carriers 558
- photo-generated carriers 558, 561, 565, 566, 573, 574
- photo generated charge carriers 582, 591
- photo generated holes 666
- photo-induced charge 324, 345, 417, 557
- photo-induced charge extraction by
 - linearly increasing voltage (photo-CELIV) method 557, 559–563, 566
- photo-oxidation process 585, 614, 615
- photon-absorption rate 603
- photon energy 294, 302, 575, 592, 594, 597, 602, 605, 667
- photostability of, polymer donors 585
- photovoltaic (PV) technology 455
- photovoltaic cells 348, 443
- photovoltaic device 242, 276, 295, 313, 315, 328, 336, 350, 354, 355, 368, 381, 397, 418, 445, 510, 606, 625
- photovoltaic external quantum efficiency 594
- photovoltaic parameters
 - for A–D–A type NF SMAs 169–170
 - for A–D–A type non-fullerene SMAs 176, 178
 - with asymmetric structures 184–185
 - with non-fused cores 194, 196
 - for A–D–A type SMAs 160, 162
 - for A-DA'D-A type non-fullerene SMAs 201, 203
 - for PDI monomer-and dimer-based NF-SMAs 146, 148
 - for PDI tetramer-based NF-SMA 154, 157
 - for PDI trimer-based NF-SMAs 150, 154
- photovoltaic technology 241, 335, 456, 487, 555, 557, 649
- P3HT:bis-TOQMF cells 135
- P3HT:OQTMF cells 136
- P3HT:tris-TOQC cells 135
- phthalocyanines (PCs) 86
- PIDTCPDT-DFBT based FET 222, 223
- PIFTBT6 based PSCs, PCEs of 217
- planar heterojunction (PHJ) device 77, 79, 80, 86, 88, 107, 276, 305, 437
- planar-structured interlayer material 508
- Planck's constant 398, 592
- plasma-etching method 537
- plastic foil substrates 647
- plastic substrates 419
- PM6:BP5T-4F-based device 208
- PM6:IDIC-based OSCs 163
- PM6:IMC6-4F based device 172
- PM6:IPTBO-4Cl based OSCs 189
- PM6:TfIF-4FIC, for tandem OSCs 395
- PM6:Y6:BTP-M OSCs 206
- polar organic solution 498
- polar solvents 419, 501, 508
- poly(3,4-ethylenedioxythiophene) (PEDOT) 496, 556
- PSS 496–501
 - quinoidal nanostructures 586
- poly(3,4-ethylenedioxythiophene)-poly(styrenesulfonate) (PEDOT:PSS) 99, 419, 473, 492, 616, 651
- poly(3-hexylthiophene) 46, 348, 629
- poly[(9,9-bis(3-(*N,N*-dimethylamino)propyl)-2,7-fluorene)-alt-2,7-(9,9-dioctylfluorene)] (PFN) 510

- poly[3-dodecylthiophene-*co*-3-(6-fullerenylhexyl)thiophene] double-cable polymer 354
- polyaniline (PANI) 424, 425
- polyelectrolyte interlayers 491
- polyethersulfone (PES) 418–420
- polyethylene (PE) 444
- polyethylene naphthalate (PEN) 418, 428, 443, 444, 482, 665, 666
substrate 482
- polyethylene terephthalate (PET) 418, 419, 421, 423–426, 429–431, 439, 444, 654, 657, 662, 668
- polyethyleneimine (PEI) 395, 398, 491, 510, 655
- polymer acceptor (PBN-10) 295, 473
- polymer backbone 28, 42, 52, 58, 255, 258, 282–284, 287, 293, 295, 296, 324, 409, 491, 607, 628
- polymer donor (CD1) 530, 473
- polymer donor materials, in tandem OSCs 388
- polymer donors based chlorinated π -bridge 46, 53, 56, 60, 61, 64, 259
- polymer donors based chlorinated backbone of A unit 256, 257, 259
- polymer donors based chlorinated D unit backbone 250–255
- polymer donors based chlorinated side chain of D unit 250–251
- polymer hole transport layer (HTL) 397, 398, 496, 497, 499–505, 651, 660
- polymer interlayers 493
- polymer PNDIO.5-based all-PSCs 282
- polymer poly(3,4-ethylenedioxythiophene):poly(styrenesulfonate) (PEDOT:PSS) 419, 432, 492, 556, 651
- polymer type OSCs 77
- polymer:fullerene system 406, 529, 540, 546
- polymer-fullerene 275, 277, 304, 305, 309, 407, 408, 414, 416, 625, 635
- polymer-nonfullerene 275, 417
- polymers structures 406–407
- polymultithiophene chain 409
- (poly- or mono-) crystalline silicon (Si)-based solar cells 647
- polyoxometalate solution 493
- polypropylene (PP) 444
- polystyrene sulfonate (PSS) 496–501, 651
- (polystyrene sulfuric acid) (PEDOT:PSS) 556
- polythiophene (PT) derived copolymers 46–48
optoelectronic properties and device performances 47, 50
- polyurethane (PU) binder 666
- porphyrin-based A–D–A donor material P1 471
- porphyrin-based molecular donors 105–107
- potential interaction energy 492
- power conversion efficiencies (PCE) 406, 456, 555, 487
of BDCPDT-based copolymer (PBDCPDT-TPD) 222
of bulk-heterojunction OSCs 335
of CO₈DFIC-based PSC 234
DC-IDT2T:PBDDTTT-T-C based PSC 225
of dithienocyclopentafluorene-based copolymer 221
of DTCC-based copolymer of PCDCBTBT 221
of FDICTF:PBDB-T based PSC 230
of fullerene-based PSCs 223
of HC-PCIC-based PSCs 266
of INPIC-4F:PBDB-T based PSCs 235
of IT-4F-based device 228
of M34:PM6 based PSCs 232
of NFBTD-based PSC 230
of NTIC:PBDB-T based PSC 226
of OSCs 1
of PaDTNTBTO:PC₇₁BM based PSCs 219
of PBDB-T:DF-PCIC based PSC 235
of PBT4Cl-Bz based PSCs 252

- power conversion efficiencies (PCE) (*contd.*)
- of PDPP5T:PC₆₁BM based single junction device 384
 - of PDTP-DFBT:PC₇₁BM single junction device 391
 - of P3FTBT6:PC₇₁BM-based device 220
 - of PIDTBT0-TT:PC₇₁BM based single-junction device 218
 - of PIDTT-DFBT:PC₇₁BM based PSC 222
 - of PIFTBT6 based PSCs 217
 - of P(IID-DTC):PC₇₁BM blend 219
 - of PIT2FBT:PC₇₁BM based devices 316
 - of PITFBT-based PSC 219
 - of P3TEA:FTTB-PDI4 devices 318
 - of PM6:M36 based PSCs 232
 - of PNDI-Si25-based all-PSCs 283
 - of PSCs 215
 - PSS2-based PSC 222
 - of PTB7-Th:IEICO-4F-based PSCs 225
 - of PTB7-Th:ITIC based PSC 228
 - PTB7-Th:IUIC blend 235
 - of PTB7-Th:NOBDT device 396
- power law dependences 561, 563, 564
- Prato reaction 129
- pre-annealed film 536
- pre-stretched elastomer 657
- printing technologies 443, 646, 647
- pristine C₆₀- and C₇₀-based solar cells performance 123–124
- pseudo-planar heterojunction (PPHJ) method 415
- PSTZ:ITIC based PSCs 320
- PTB7-Th:F8IC:PC₇₁BM based ternary OSCs 173
- PTB7-Th:FNIC2 based blend 176
- PTB7-Th:T2 based device 181
- P3TEA:SF-PDI₂ based OSC 317
- PTTEA:Alq₃-PDI₂ based OSCs 152
- PTTEA:TPO-PDI based OSCs 152
- p*-type and *n*-type semiconductors 77, 304, 487, 519–520
- p*-type molecular photovoltaic materials, in SP-SMSCs 89
- benzodithiophene-based A–D–A-type molecular donors 90–95
- D1-A-D2-A-D1-type molecular donors 96–99
- dithienopyrrole-based A–D–A-type molecular donors 96
- dithienosilole-based A–D–A-type molecular donors 95–96
- oligothiophene-based A–D–A-type molecular donors 89–90
- other molecular donors 107–110
- porphyrin-based molecular donors 105–107
- p*-type molecular photovoltaic materials, in VD-SMSCs
- borondipyrromethenes-based molecular donors 83–85
- D-A-A'-type SMDs 80–83
- merocyanines 86
- OT-based SMDs 79
- phthalocyanines 86
- PV cell testing system 460
- r**
- radiative decay rate 599–600, 609
- radiative recombination loss 313, 594, 596, 600
- radiative recombination voltage loss 375, 595, 599, 605–606, 609
- random terpolymerization 282–283
- reduced charge recombination loss 581
- reduced graphene oxide (rGO) 426–428, 512
- reflectance geometry 527
- reflective rear metal cathode 556
- regioisomers, of fullerene bisadducts 134
- regioselective synthesis, of isomer-free fullerene bisadducts 134
- relief printing method 443
- renewable energy sources 613
- reorganization energies 322, 601, 603
- resistivity 446

- resonant soft X-ray scattering (RSoXS) 533, 534, 546
- reverse bias 523, 560, 573–574, 583
- ring-fusion strategy 150
- roll-to-roll (R2R) technology 405, 443–445
- roll-to-roll slot-die printing method 428
- root-mean squared surface roughness value 478
- S**
- scalable purification processes 484
- scanning electron microscopy (SEM) 430–431, 495, 572, 573
- scanning probe microscopy (SPM) 521
- scanning transmission X-ray microscopy (STXM) 525–526
- scattering intensity 526–527, 533–534
- scattering length densities (χ) 536–537
- scattering methods 526–534
- scattering pattern 531, 541
- screen-printed silver grids 443
- screen printing 381, 405, 436, 442–444, 646
- secondary ion mass spectrometry (SIMS) 535–537
- segregation of, donor/acceptor 576
- selenium-substituted Y6 derivative 208
- selenophene-containing FREAs 189
- self-doping organic semiconductors 493
- self-doping property 493
- self-powered solar glasses 668
- semitransparent Al cathode 567
- semitransparent device 83, 650
- semitransparent foldable-flexible OSCs 654–655
- semitransparent OSCs based on chlorinated SMAs 268–269
- sheet resistances (R_s) 420, 424–427, 429, 431, 443, 446, 478, 567, 571
- Shockley–Quessier theory 593, 595, 607
- short circuit current density (J_{SC}) 460, 488, 558, 591
- of photovoltaic devices 313
- shunt resistance (R_{SH}) 425, 477, 559
- side chain engineering 43, 49, 54, 90, 191–192, 199, 201, 221, 232, 252, 278–279, 282, 287, 329, 408–409, 623
- side chain isolation design 47
- side-chain engineering strategy 282, 287
- signal-to-noise ratio (S/N) 533, 657
- silver (Ag) nanowire 429
- silver based screen-printable metal inks 443
- single-component organic solar cells (SCOSCs)
- based on pristine conjugated materials 336
- challenges 375–376
- charge generation process 375
- morphological studies, of photo-active layers 361–362
- block copolymers 366–367
- double-cable polymer-based SCOSCs 367–375
- molecular dyads 362–366
- performance enhancement 375
- single-component conjugated materials for 336
- block copolymers 345–350
- double-cable conjugated polymers for 350–361
- molecular dyads 336–344
- single fullerene-attached diblock double-cable conjugated polymer 354
- single junction all-polymer BHJ solar cells 277
- single-junction solar cells 381, 456
- single-wall carbon nanotubes (SWCNTs) 423–426, 504
- skin-wearable application 646, 669
- slip-stacked acceptor, of phenyl-PDI 146
- slot-die coating 405, 410, 429, 436, 438–439, 441, 444–445, 472, 488, 646
- small angle scattering (SAS) 253, 326, 526

- small molecule acceptor materials (SMAs)
 - 77, 145–210, 215–237, 241, 244,
 - 262–264, 266, 268–270, 315–328,
 - 394, 396, 412, 625
 - in tandem OSCs 390
- small-molecule-donor:fullerene 538
- small molecule donor materials (SMDs)
 - 77–115, 125, 146, 242, 260, 269,
 - 330, 392, 410, 415, 417, 538, 540,
 - 631
 - in tandem OSCs 389
- small molecular donors 260, 411, 417,
- 462, 472
- small molecule interlayer materials
- 507–508
- small-molecule non-fullerene acceptor
- IT-4F 412, 482–483
- small-molecule semiconductors 410
- small-molecule type OSCs 77
- smaller fullerenes 121–122
- smart windows 449, 650–651, 669
- sol-gel process 571
- solar cell devices 487–489, 492–494, 499,
- 503–506, 508–509, 512, 604
- solar cell interlayer applications 508
- solar energy 1, 215, 455, 487, 645, 647,
- 661, 666
- solar park 646, 648–650, 669
- solar simulator 460, 557, 656
- solid additive 547–549, 631–632
- solution processability 29, 216, 493,
- 512–513
- solution processing technology 502
- solution-based R2R coating 646
- solution-processed antimonene layer
- 580, 528
- solution-processed polymer solar cells
- 215
- solution-processed SMSCs (SP-SMSCs)
- 78, 111
- with non-fullerene small molecule
- acceptors
 - binary solar cells 111
 - ternary solar cells 112–114
- solvent additive 219, 298, 304, 362, 498,
- 544–547, 576, 627, 631–633
- solvent annealing 298, 304, 341, 356,
- 408, 524–525, 540–541, 550–551
- solvent evaporation rate 436, 542
- solvent vapour annealing (SVA) 92, 94,
- 111–112, 351, 362, 364, 286, 317,
- 351, 364, 540–542, 609
- source measure units (SMU) 460
- space charge limited current (SCLC) test
- 250, 361, 564
- spectral luminosity factor 460
- spin-coating process of all-polymer BHJ
- blend 304
- spin-coating the polymer 559
- spray coating 405, 436, 441–442, 444,
- 488, 646
- spray deposition process 442
- squaraine (SQ) series SMDs 108, 125
- stability enhancements, of all-PSCs 307
- stability enhancements, of PSCs
 - ambient stability 308
 - mechanical stability 308–309
 - photo stability 309–310
 - thermal stability 307–308
- stability, of organic solar cells 584–586
- stacked planar structure 660
- π - π stacking 26, 40, 42, 53, 62, 68, 83, 92,
- 101, 105, 110, 156–157, 160, 163,
- 165–166, 168–169, 172, 183–184,
- 187, 189, 191–193, 198–199, 204,
- 232–233, 247–248, 252, 296–297,
- 319, 363, 365, 368, 410, 412, 475,
- 508, 510, 529, 538–539, 541–542,
- 544, 547, 549
- standard PV cells 460
- standard sensitivity curve $V(\lambda)$ 459
- star-like small molecules 507–508
- state-of-the-art devices 417
- static dipole moment 601, 603
- step-like function 592, 594–595, 606
- Stille coupling 279, 344, 349
- S(TPA-PDI) 152
- structural homogeneity 500
- styrene sulfonic acid constituents 497

- styryl-functionalized triaryl-amine-based material (DVTPD) 503
- sublevel electronic states 570, 575
- SubPc/C₆₀-based PHJ cell 88
- subtle nanometer-scale morphology 617
- sulfated graphene oxide (GO-OSO₃H) 504
- sulfobetaine (SB) zwitterions 491
- sulfobetaine side chains 495
- sulfobetaine-substituted zwitterionic fullerene (C₆₀-SB) 509
- sulfonated poly(phenylsulfone) (SPS) 492
- super conductivity 429
- super transmittance 423
- superior charge collection capability 581
- surface polarization 491
- surface sensitive techniques 521, 535
- Suzuki–Miyaura polycondensation 345
- synBTDC 83
- synthesized perylene diimides (PDI)s–based polyelectrolytes 493
- t**
- α-6T 80, 110
- tandem all-PSCs 305, 308
- tandem OSCs
- active layer materials 383
 - fullerene acceptors 384–393
 - non fullerene acceptors 393–397
 - functional layers and energy level arrangement 382
 - interconnecting layer materials 397–398
 - semi-empirical analysis of 398–400
 - thermalization and transmission losses 382
- TAPC-based device 88
- Ta-PDI-based OSC 152
- TAz-containing WBG polymer 60
- temperature-dependent aggregation 9, 252, 408–409, 544, 550
- temporal instability 460
- ternary all-PSCs 305
- ternary blending strategy 413
- ternary configurations 416
- ternary organic solar cell 413, 414
- ternary SMSCs 112
- ternary system 394, 406, 413–415
- terpolymerization strategy 286
- terrestrial photovoltaic (PV) modules 617
- terthiophene-based D–A polymer 29
- terthiophene-based LBG copolymers 216
- tether-directed remote functionalization 134
- tetrabromothiophene (Br-ADD) 547
- tetrafluorinated benzene (PF4) 409
- tetrahydrofuran (THF) 63, 209, 327, 437, 498, 540
- tetrahydrofuran/isopropyl alcohol (THF/IPA) 437, 544
- 5,5,12,12-tetrakis(4-hexylphenyl)-indacenobis(dithieno[3,2-*b*:2',3'-*d*]pyrrol) (INP) 167
- 6,6,12,12-tetrakis(4-hexylphenyl)-indacenobis(dithieno[3,2-*b*:2',3'-*d*]thiophene) (IBDT) 167
- tetraphenyl dibenzoperiflanthene (DBP):C₇₀ cells 125, 639
- textile-based wearable OSCs 659
- theoretical fitting 562
- thermal annealing process 92, 174, 181, 183, 193, 198–199, 230, 276, 297, 300, 304, 317, 348, 351, 354, 361–362, 364–365, 372, 408, 411, 425, 505, 531, 538–540, 550, 556, 627, 629, 632, 635, 661
- thermal energy 538, 540, 653
- thermal excitation 599
- thermal-driven D/A lamellar phase separation 358
- thermal-induced aggregation 615
- thermodynamic non-equilibrium state 623
- [1,2,5]Thiadiazolo[3,4-*f*]isoindole-5,7-dione (TID) 6
- thiazolothiazole 46, 411

- thick film application 408
 - thick photoactive layer 480, 567
 - thick-film active layer 406, 411
 - thick-film fullerene-based OSCs 410
 - thick-film nonfullerene OSCs 411
 - thick-film polymer-fullerene binary devices 407, 408
 - thick-film ternary organic solar cells 414
 - thickness of, active layer 603
 - thieno[2,3-*f*]benzofuran derived polymers 28
 - thieno[3,4-*b*]thiophene-derived copolymers
 - chemical structures 42
 - optoelectronic properties and device performances 43–45
 - thieno[3,4-*c*]pyrrole-4,6-dione (TPD)-derived copolymers 35
 - optoelectronic properties and device performances 38, 39, 41
 - using thiophene derivatives 37
 - thin film photovoltaics 493
 - thin-film solar cells 455
 - thiophenes 607
 - carbon-carbon (double bond) π^* absorption 495
 - ring-fused PDI dimers 149–150
 - terminated isoindigo polymers 13
 - third-generation photovoltaic cells 456
 - three-dimensional (3D) interlayer materials 513
 - TIDT-BT-R2 324
 - TIDT-BT-R6 324
 - total current density 593
 - total decay rate 599
 - total integrated scattering intensity (TSI) 534
 - total recombination rate 595
 - TPTT-IC based PSC 226
 - traditional optical microscopy 524
 - transient absorption spectrum (TAS) 309, 562–563
 - transient photocurrents 557, 566–569, 583
 - transition dipole moment (TDM) 535, 602–603, 608
 - transmission electron microscopy (TEM) 17–18, 193, 297–298, 362–367, 370, 420, 524–525, 545–546, 551, 580, 582
 - transmission scattering geometry 527
 - transparent bottom anode materials 429
 - transparent electrodes 419–434, 442–443, 447, 498, 506, 654, 660, 668
 - transparent indium tin oxide (ITO) anode 556
 - transparent metal oxide electrodes 421
 - transparent plastic substrate 418
 - triazine core (Tf1 and Tf2) 508
 - triazine core (TzPyBr) 507
 - triphenylamine (TPA) 101, 126, 152, 503, 506
 - triphenylamine, polyperfluorocyclobutane (TPA-PFCB) 503
 - tris-PC61BM 135
 - tunable infrared laser (IR-AFM) 524
 - tuning absorption spectra, polymer acceptors based on B←N unit 294–295
 - twisted PDI-based SMAs 146
 - two-dimension carbon nanomaterials 426
 - TZNT-based WBG polymer donors 56
- u**
- ultra-high vacuum (UHV) deposition chamber 577
 - ultrathin ZnO 557–559, 571
 - ultraviolet photo-electron spectroscopy (UPS) 495, 535, 566, 580
 - ultraviolet range 458
 - unbalanced charge mobility 556
 - unconventional fullerene acceptors 136–138
 - unfavorable exciton dissociation 545, 568–569

V

- vacuum deposition 78, 86, 442, 557
- vacuum-deposited iBuBTDC:C₇₀ cells 125
- vacuum-deposited SMSCs (VD-SMSCs) 78
 - oligothiophene-based molecular donors 79–80
 - power conversion efficiency 78
- van der Waals forces 521
- variable-angle spectroscopic ellipsometry (VASE) 537
- vertical q_z direction 528
- vibrationally resonant sum frequency
 - generation spectroscopy (VR-SFG) 495–496
- vibronic coupling 606
- visual function 459
- V_{loss} , defined 375
- V_{oc} of organic solar cells
 - charge transfer states 596–597
 - charge transfer states
 - CT state vs. V_{oc} 597–600
 - K_r and K_{nr} 601–604
 - CT state related parameters 604–606
 - strategies to reduce V_{nr} and V_r 606–609
- voltage loss 591–596

W

- water soluble sulfobutylated phenol
 - formaldehyde resin (BSPF) 500
- wearable electronics 655–656, 661–662
- white light-emitting diodes (LEDs) 315, 456
- wide angle scattering (WAS) 526
- wide bandgap (WBG) polymers
 - based on benzodithiophene-*alt*-thiophene derivatives 49–50
 - based on benzothiadiazole (BT) derivatives 50–53

- based on polythiophene (PT)

- derivatives 46–48

- based on thiazole, pyrazine and derivatives containing

- N*-heterocycles 56–61

- benzo[1,2-*c*:4,5-*c'*]dithiophene-4,8-dione derivatives 61–66

- donor categories 46

- others 66–68

- wide interlayer thickness range 493

- wide-bandgap materials 461, 473

- Wülfel's generalized Planck law 592, 594

X

- X-ray photoelectron spectroscopy (XPS) 535–537, 549–550, 566, 575–577, 579
- X-ray reflectivity (XRR) 536–537

Y

- Y6 30, 52, 56, 60, 63–64, 67–68, 111, 172, 204–210, 216, 233, 236, 241, 260, 397, 412, 437, 540, 542–543, 549, 645
 - type SMAs 300, 302
- Y11 based device 201, 204
- Y-series NFAs 200, 236
- yellow phosphor 458

Z

- zero-loss filtered image 524
- zigzag naphtho[1,2-*b*:5,6-*b'*]dithiophene (zNDT) 44–45
- ZnO electron extraction layer (EEL) 557–563, 565, 570–572
- ZnO interlayer 561–565, 567, 569–576, 578–579
- ZnO nanoparticles (NPs) 478
- Zwitterions 491–492, 495, 509, 513

